

Form PTO-1449 (Rev. 8-83)		U.S. Department of Commerce Patent and Trademark Office		Attorney Docket N. 0756-2203		Serial No. 09/583087	
RECEIVED INFORMATION DISCLOSURE STATEMENT SEP 05 2000 (Use several sheets if necessary)				Applicant: Shunp i YAMAZAKI			
				Filing Date: September 5, 2000		Group:	
OFFICE OF PETITIONS U.S. PATENT DOCUMENTS							
Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)	
3/06	5,250,931*	10/1993	Misawa et al.				
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Examiner J. Jochan			Date Considered 10/01				
*EXAMINER: Initial citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

Form PTO-1449
(Rev. 8-83)U.S. Department of Commerce
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Applicant: Shumpei YAMAZAKI

Filing Date: September 5, 2000

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Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
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						Yes	No
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	3-246973	11/05/91	JP			Abstract	
	4-245655	09/02/92	JP			Abstract	
	92-18644	10/22/92	Korea				X
	90-17171	11/15/90	Korea				X
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	5-134272*	05/1993	JP			Abstract	
	6-88971*	03/1994	JP			Abstract	
	2-208635*	08/1998	JP			Abstract	
		08/20/90					
Examiner <i>J. Mahon</i>		Date Considered 10/01					

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Form PTO-1449 (Rev. 8-83)		U.S. Department of Commerce Patent and Trademark Office		Attorney Docket No. 0756-2230	Serial No. 09/583087
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)				Applicant: Shunpei YAMAZAKI	
				Filing Date: September 5, 2000	
OFFICE OF PETITIONS				Group:	
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*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.					
*Reference cited in parent application S.N. 08/962,601					